NSN 5961-01-235-3270

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view Online at https://aerobasegroup.com/nsn/5961-01-235-3270
Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.750 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-72
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.071 inches
Features Provided:
Hermetically sealed case and quality assurance level s
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current
Power Rating Per Characteristic:
200.0 milliwatts small-signal input power, common-collector preset
Transfer Ratio:
30.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
4 uninsulated wire lead

Shelf Life: NI/o

Specification Data:

81349-mil-s-19500/426 government specification

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Demilitarization:

No

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